



Product data sheet

1. Product profile

1.1 General description

Passivated, sensitive gate thyristors in a SOT54 plastic package.

1.2 Features

Designed to be interfaced directly to microcontrollers, logic integrated circuits and other low power gate trigger circuits.

1.3 Applications

General purpose switching and phase control applications.

1.4 Quick reference data

- V_{DRM} , $V_{RRM} \le 200 V$ (BT169B)
- $\bullet V_{\text{DRM}}, V_{\text{RRM}} \le 400 \text{ V (BT169D)}$



2. Pinning information

Table 1:	Discrete pinning	
Pin	Description	Simplified outline Symbol
1	anode (a)	
2	gate (g)	
3	cathode (k)	sym037
		SOT54 (TO-92)



3. Ordering information

Table 2: Order	ring informat	ion				
Type number	Package	Package				
	Name	Description	Version			
BT169B	-	plastic single-ended leaded (through hole) package; 3 leads	SOT54			
BT169D						
BT169G						

4. Limiting values

Table 3: Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM} , V _{RRM}	repetitive peak off-state voltages				
	BT169B		<u>[1]</u> -	200	V
	BT169D		<u>[1]</u> -	400	V
	BT169G		<u>[1]</u> -	600	V
I _{T(AV)}	average on-state current	half sine wave; T _{lead} ≤ 83 °C; see <mark>Figure 1</mark>	-	0.5	A
I _{T(RMS)}	RMS on-state current	all conduction angles; see <mark>Figure 4</mark> and <u>5</u>	-	0.8	A
I _{TSM}	non-repetitive peak on-state current	half sine wave; T _j = 25 °C prior to surge; see <u>Figure 2</u> and <u>3</u>			
		t = 10 ms	-	8	А
		t = 8.3 ms	-	9	А
l ² t	I ² t for fusing	t = 10 ms	-	0.32	A ² s
dI _T /dt	repetitive rate of rise of on-state current after triggering	$I_{TM} = 2 \text{ A}; I_G = 10 \text{ mA};$ dI _G /dt = 100 mA/ μ s	-	50	A/µs
I _{GM}	peak gate current		-	1	А
V _{GM}	peak gate voltage		-	5	V
V _{RGM}	peak reverse gate voltage		-	5	V
P _{GM}	peak gate power		-	2	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.1	W
T _{stg}	storage temperature		-40	+150	°C
Tj	junction temperature		-	125	°C

[1] Although not recommended, off-state voltages up to 800 V may be applied without damage, but the thyristor may switch to the on-state. The rate of rise of current should not exceed 15 $A/\mu s$.

BT169 series

Thyristors logic level



BT169 series

Thyristors logic level





4 of 12

Thyristors logic level

Thermal characteristics 5.

Table 4:	Thermal characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-lead)}	thermal resistance from junction to lead		-	-	60	K/W
R _{th(j-a)}	thermal resistance from junction to ambient	printed-circuit board mounted; lead length = 4 mm	-	150	-	K/W



6. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
I _{GT}	gate trigger current	V _D = 12 V; I _T = 10 mA; gate open circuit; see <mark>Figure 8</mark>	-	50	200	μA
L	latching current	V_D = 12 V; I _{GT} = 0.5 mA; R _{GK} = 1 kΩ; see <u>Figure 10</u>	-	2	6	mA
Ін	holding current	V_D = 12 V; I _{GT} = 0.5 mA; R _{GK} = 1 kΩ; see <u>Figure 11</u>	-	2	5	mA
V _T	on-state voltage	I _T = 1.2 A	-	1.25	1.7	V
V _{GT}	gate trigger voltage	I _T = 10 mA; gate open circuit; see <u>Figure 7</u>				
		V _D = 12 V	-	0.5	0.8	V
		$V_D = V_{DRM(max)}; T_j = 125 \ ^{\circ}C$	0.2	0.3	-	V
I _D , I _R	off-state leakage current	$ V_D = V_{DRM(max)}; V_R = V_{RRM(max)}; $	-	0.05	0.1	mA
Dynamic o	haracteristics					
dV _D /dt	critical rate of rise of off-state voltage	$V_{DM} = 67 \% V_{DRM(max)}; T_j = 125 °C;$ exponential waveform; see <u>Figure 12</u>				
		$R_{GK} = 1 k\Omega$	500	800	-	V/μs
		gate open circuit	-	25	-	V/μs
t _{gt}	gate controlled turn-on time	$\begin{split} I_{TM} &= 2 \text{ A}; V_D = V_{DRM(max)}; \\ I_G &= 10 \text{ mA}; dI_G/dt = 0.1 A/\mu s \end{split}$	-	2	-	μs
t _q	circuit commuted turn-off time		-	100	-	μs

BT169 series

Thyristors logic level



BT169 series

Thyristors logic level



7. Package information

Epoxy meets requirements of UL94 V-0 at 1/8 inch.

BT169 series

Thyristors logic level

8. Package outline



Fig 13. Package outline.

BT169 series

Thyristors logic level

9. Revision history

Table 6: Revision	history				
Document ID	Release date	Data sheet status	Change notice	Order number	Supersedes
BT169_SERIES_4	20040823	Product data sheet	-	9397 750 13512	BT169_SERIES_3
Modifications:	information • <u>Section 1.</u> • <u>Table 2 "O</u>	t of this data sheet has in standard of Philips Se 4 "Quick reference data" rdering information": BT miting values": BT169E	miconductors. : BT169E obsolete, 169E obsolete, remo	removed from list. oved from table.	v presentation and
BT169_SERIES_3	20010902	Product specification	-	not applicable	BT169_SERIES_2
BT169_SERIES_2	20010901	Product specification	-	not applicable	BT169_SERIES_1
BT169_SERIES_1	19970901	Product specification	-	not applicable	-

BT169 series

10. Data sheet status

Level	Data sheet status [1]	Product status [2] [3]	Definition
I	Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
II	Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
III	Product data	Production	This data sheet contains data from the product specification. Philips Semiconductors reserves the right to make changes at any time in order to improve the design, manufacturing and supply. Relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN).

[1] Please consult the most recently issued data sheet before initiating or completing a design.

[2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

[3] For data sheets describing multiple type numbers, the highest-level product status determines the data sheet status.

11. Definitions

Short-form specification — The data in a short-form specification is extracted from a full data sheet with the same type number and title. For detailed information see the relevant data sheet or data handbook.

Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information — Applications that are described herein for any of these products are for illustrative purposes only. Philips Semiconductors make no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

12. Disclaimers

Life support — These products are not designed for use in life support appliances, devices, or systems where malfunction of these products can reasonably be expected to result in personal injury. Philips Semiconductors customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Philips Semiconductors for any damages resulting from such application.

Right to make changes — Philips Semiconductors reserves the right to make changes in the products - including circuits, standard cells, and/or software - described or contained herein in order to improve design and/or performance. When the product is in full production (status 'Production'), relevant changes will be communicated via a Customer Product/Process Change Notification (CPCN). Philips Semiconductors assumes no responsibility or liability for the use of any of these products, conveys no license or title under any patent, copyright, or mask work right to these products are free from patent, copyright, or mask work right infringement, unless otherwise specified.

13. Contact information

For additional information, please visit: http://www.semiconductors.philips.com For sales office addresses, send an email to: sales.addresses@www.semiconductors.philips.com

BT169 series

Thyristors logic level

14. Contents

1	Product profile
1.1	General description
1.2	Features
1.3	Applications 1
1.4	Quick reference data
2	Pinning information
3	Ordering information 2
4	Limiting values 2
5	Thermal characteristics5
6	Characteristics 6
7	Package information 8
8	Package outline 9
9	Revision history 10
10	Data sheet status
11	Definitions 11
12	Disclaimers 11
13	Contact information 11



© Koninklijke Philips Electronics N.V. 2004

All rights are reserved. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice. No liability will be accepted by the publisher for any consequence of its use. Publication thereof does not convey nor imply any license under patent- or other industrial or intellectual property rights.

Date of release: 23 August 2004 Document order number: 9397 750 13512

Published in The Netherlands